

SPLIT-CHANNEL HIGH ELECTRON MOBILITY TRANSISTOR (HEMT) DEVICE

Philbert F. Marsh et al.

RTN2-152PUS

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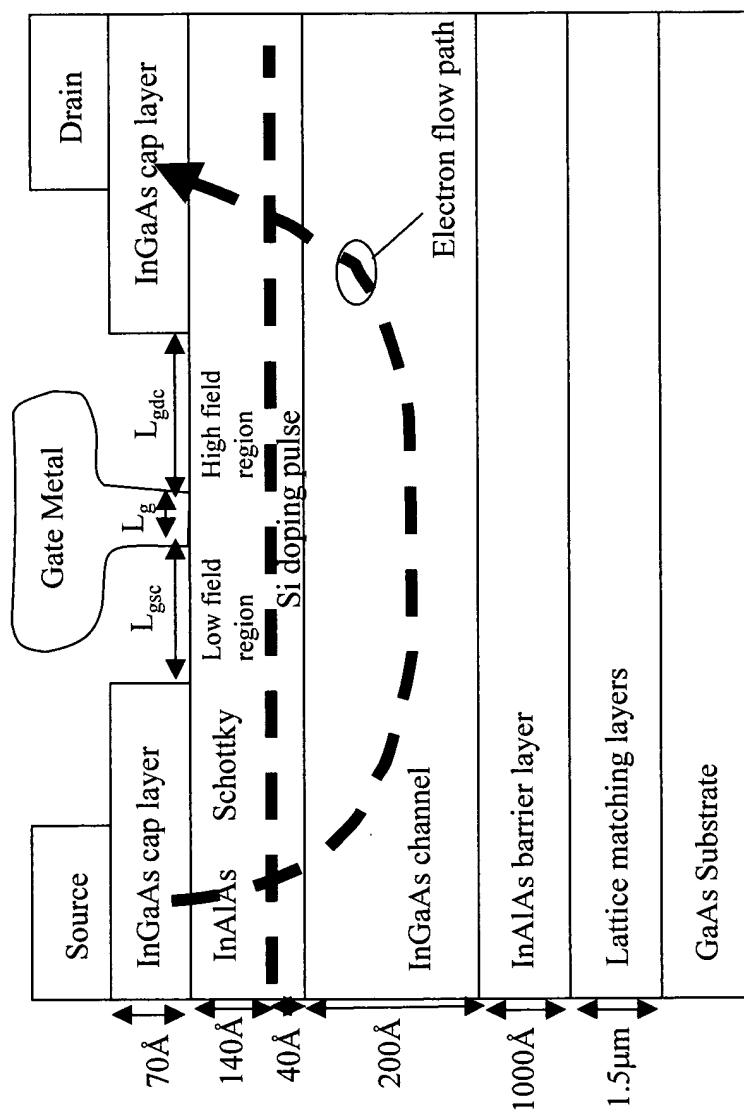


Fig 1

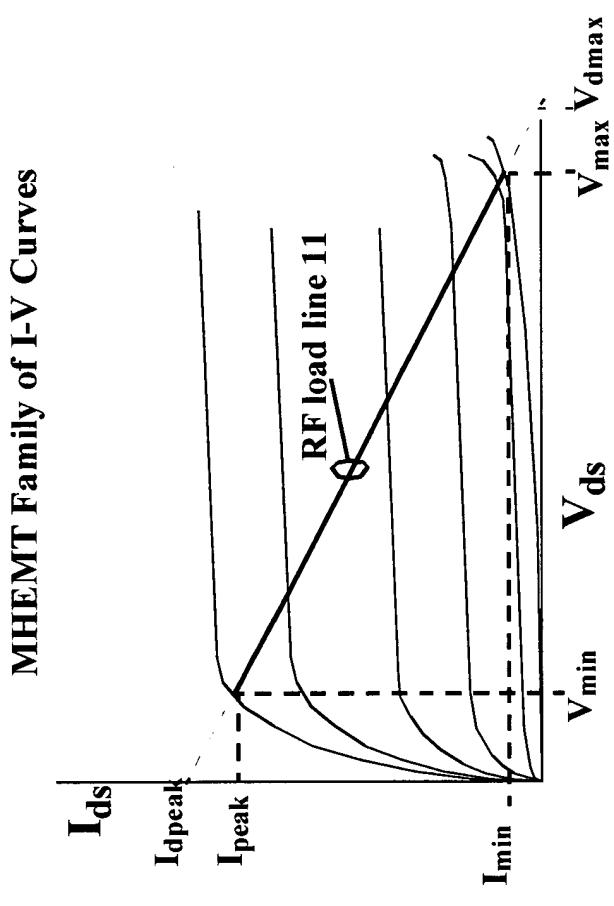


Fig 2

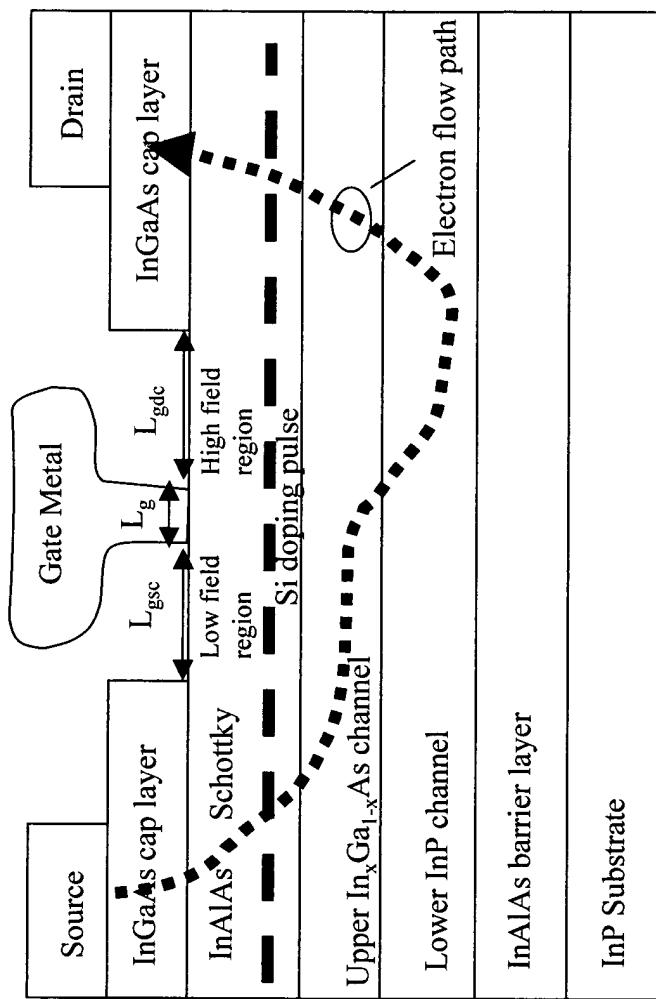
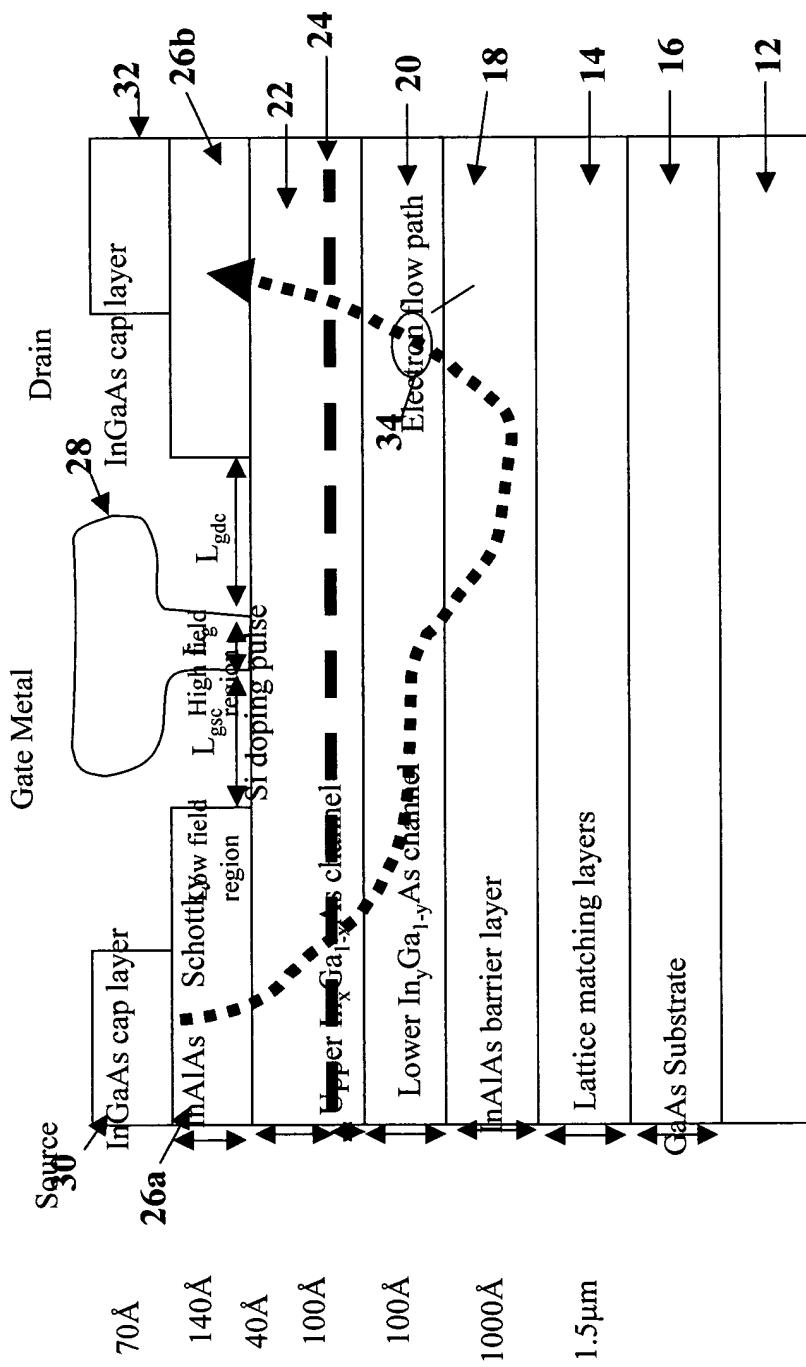


Fig 3

Fig 4
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X02M124-2 postgate

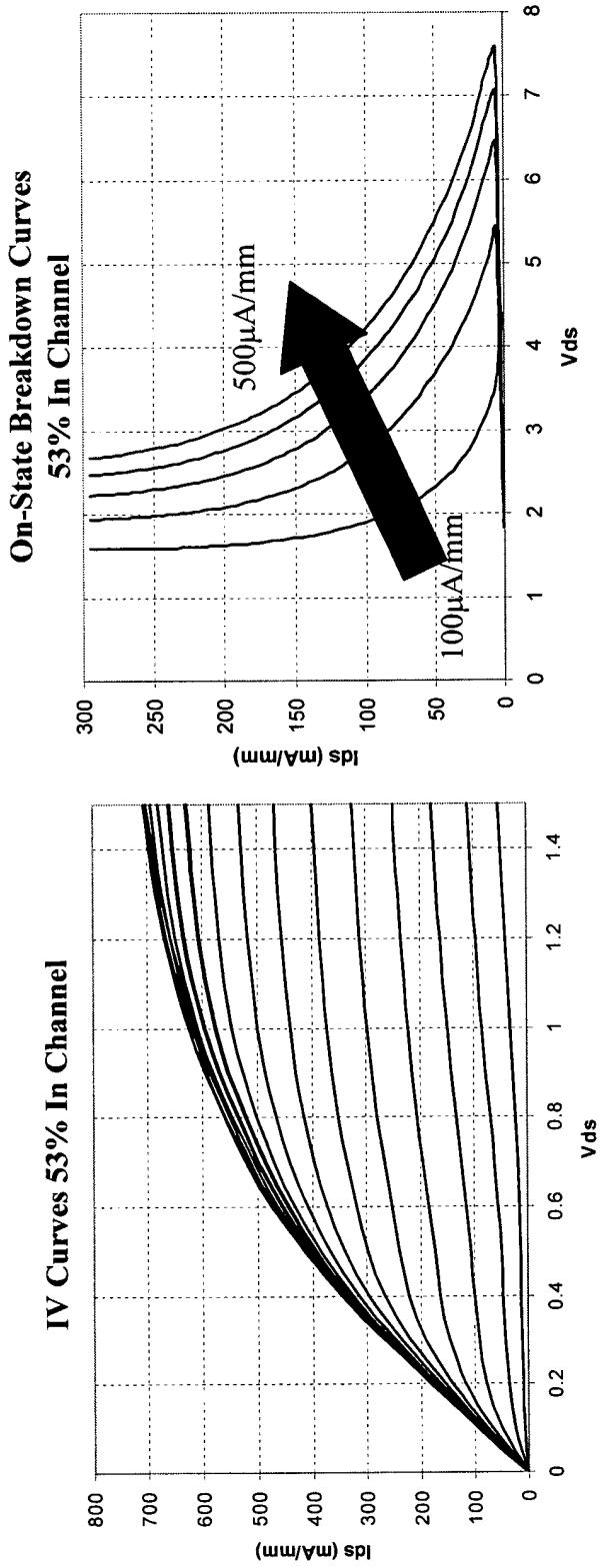


Fig 5

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X02M124-3 Postgate

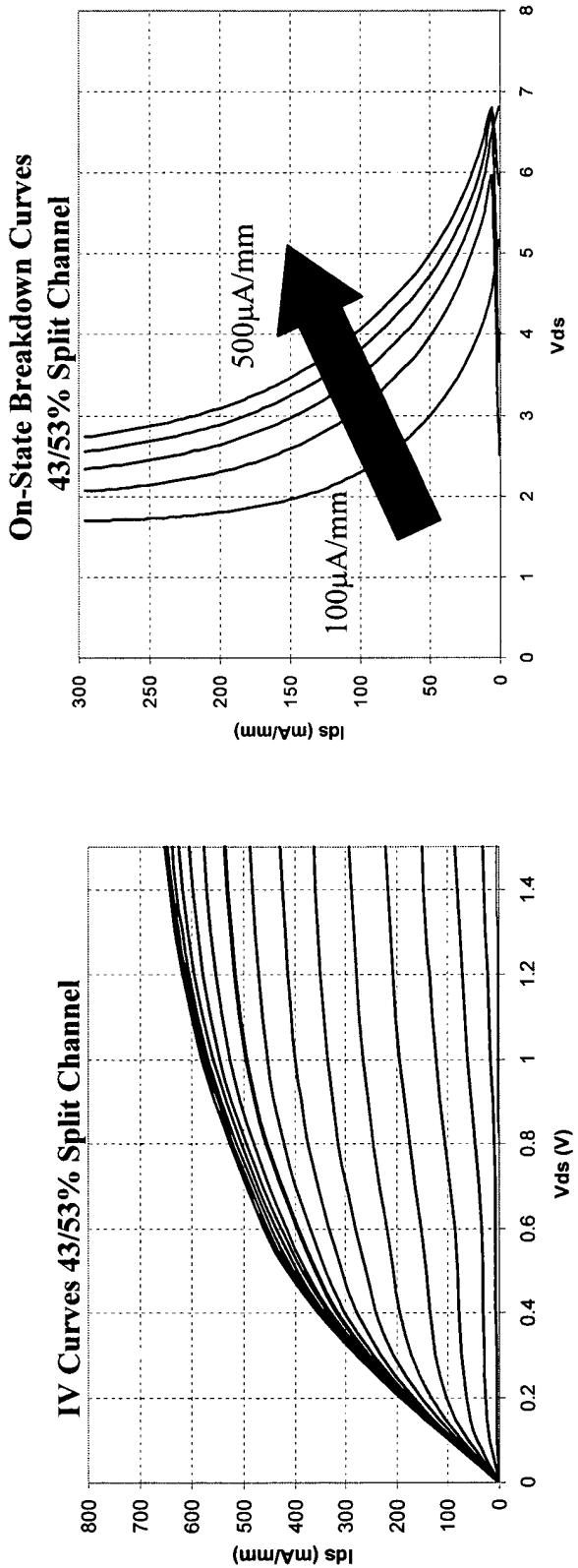


Fig 6

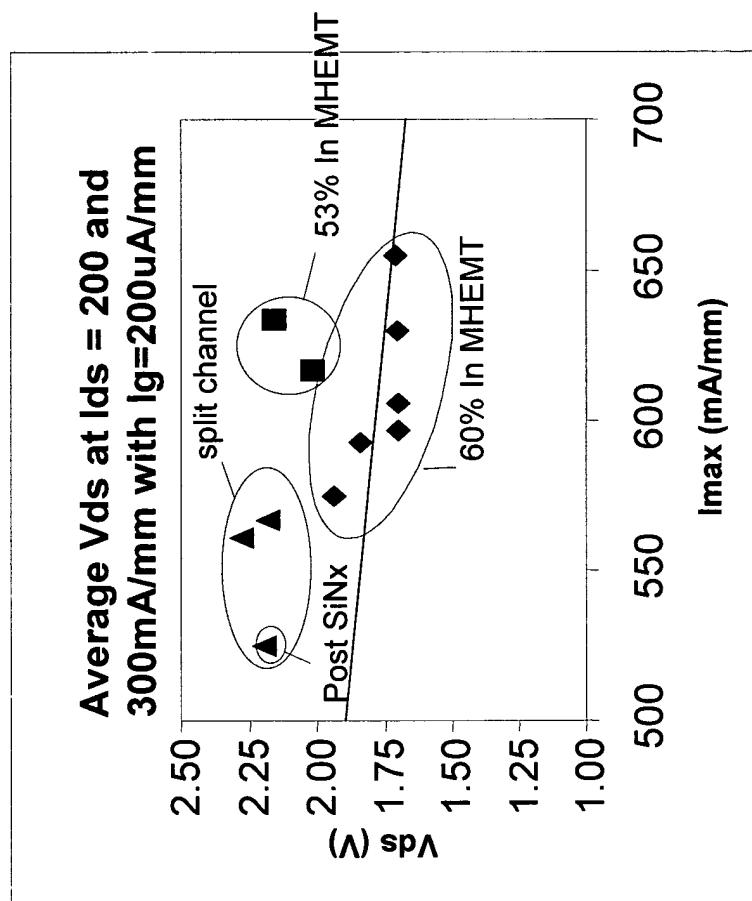


Fig 7

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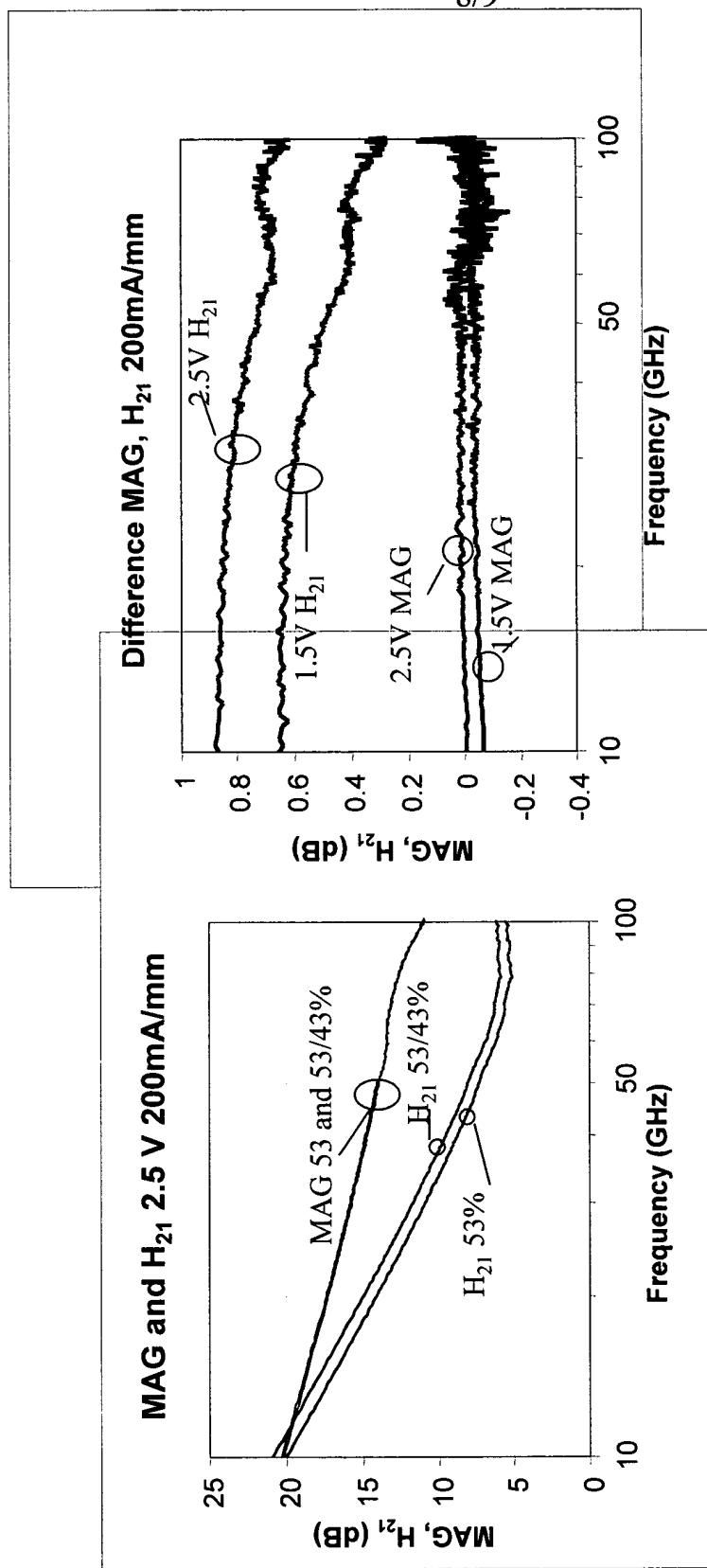


Fig 8

Fig 9

X02M124-3 150um total gate width

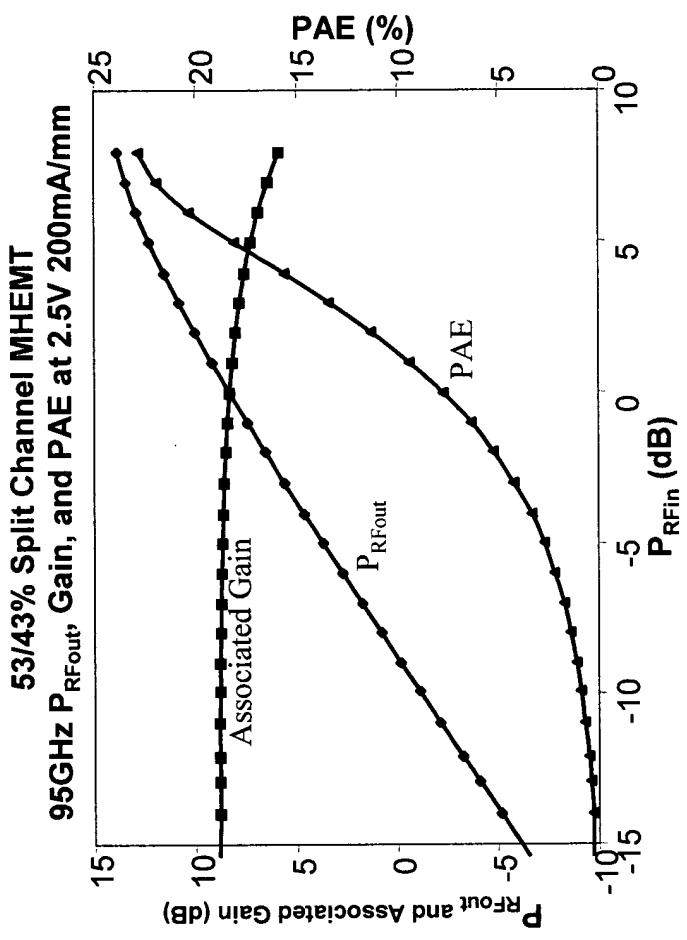


Fig 10